

DATA SHEET

74LVCU04A Hex inverter

Product specification
Supersedes data of 2003 Sep 01

2004 Mar 12

Hex inverter

74LVCU04A

FEATURES

- Wide supply voltage range from 1.2 V to 3.6 V
- Inputs accept voltages up to 5.5 V
- CMOS low-power consumption
- Direct interface with TTL levels
- In accordance with JEDEC standard no. 8-1A
- ESD protection:
HBM EIA/JESD22-A114-A exceeds 2000 V
MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$.

DESCRIPTION

The 74LVCU04A is a high-performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

The 74LVCU04A is a general purpose hex inverter. Each of the six inverters is a single stage with unbuffered outputs.

QUICK REFERENCE DATA

GND = 0 V; $t_r = t_f \leq 2.5\text{ ns}$; $T_{\text{amb}} = 25\text{ }^{\circ}\text{C}$.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
$t_{\text{PHL}}/t_{\text{PLH}}$	propagation delay nA to nY	$C_L = 50\text{ pF}$; $V_{\text{CC}} = 3.3\text{ V}$	2.1	ns
C_I	input capacitance		5.5	pF
C_{PD}	power dissipation capacitance per gate	notes 1 and 2	8.5	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{\text{PD}} \times V_{\text{CC}}^2 \times f_i \times N + \Sigma(C_L \times V_{\text{CC}}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

$\Sigma(C_L \times V_{\text{CC}}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_i = \text{GND to } V_{\text{CC}}$.

FUNCTION TABLE

See note 1.

INPUT		OUTPUT	
nA		nY	
L		H	
H		L	

Note

1. H = HIGH voltage level;
L = LOW voltage level.

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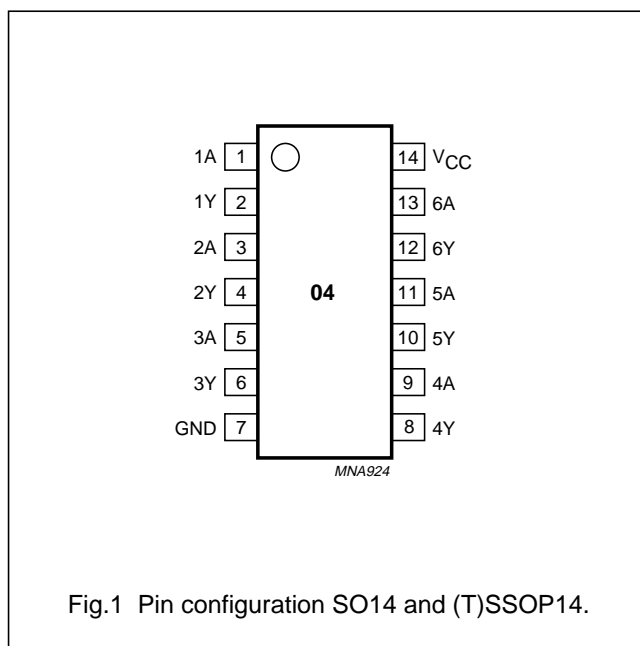
74LVCU04A

ORDERING INFORMATION

TYPE NUMBER	PACKAGE				
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE
74LVCU04AD	-40 °C to +125 °C	14	SO14	plastic	SOT108-1
74LVCU04ADB	-40 °C to +125 °C	14	SSOP14	plastic	SOT337-1
74LVCU04APW	-40 °C to +125 °C	14	TSSOP14	plastic	SOT402-1
74LVCU04ABQ	-40 °C to +125 °C	14	DHVQFN14	plastic	SOT762-1

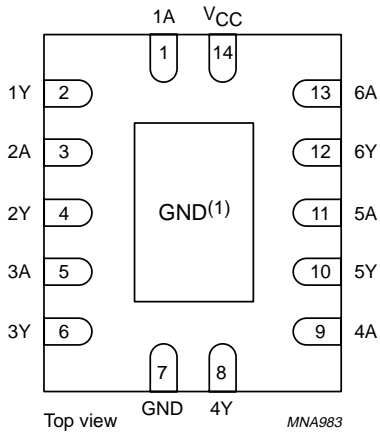
PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	1Y	data output
3	2A	data input
4	2Y	data output
5	3A	data input
6	3Y	data output
7	GND	ground (0 V)
8	4Y	data output
9	4A	data input
10	5Y	data output
11	5A	data input
12	6Y	data output
13	6A	data input
14	V _{CC}	supply voltage



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(1) The die substrate is attached to this pad using conductive die attach material. It can not be used as a supply pin or input.

Fig.2 Pin configuration DHVQFN14.

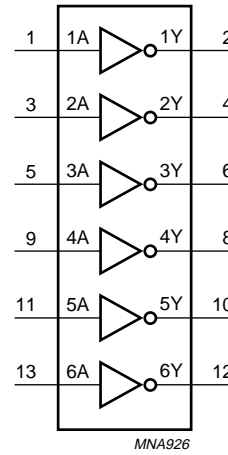


Fig.3 Logic symbol.

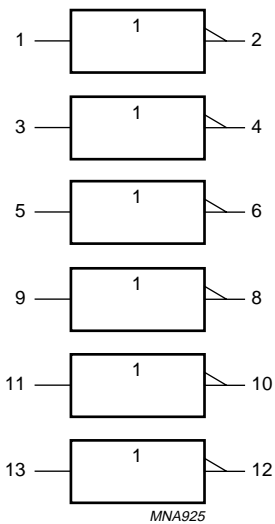


Fig.4 Logic symbol (IEC).

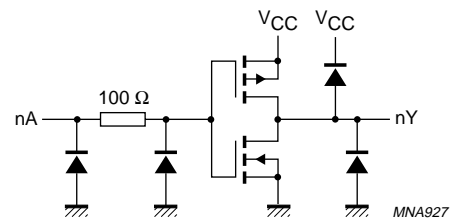


Fig.5 Schematic diagram (one inverter).

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage	for maximum speed performance	2.7	3.6	V
		for low-voltage applications	1.2	3.6	V
V_I	input voltage		0	5.5	V
V_O	output voltage		0	V_{CC}	V
T_{amb}	ambient temperature	in free air	-40	+125	°C
t_r, t_f	input rise and fall times	$V_{CC} = 1.2\text{ V to }2.7\text{ V}$	0	20	ns/V
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		-0.5	+6.5	V
I_{IK}	input diode current	$V_I < 0\text{ V}$	-	-50	mA
V_I	input voltage	note 1	-0.5	+6.5	V
I_{OK}	output diode current	$V_O > V_{CC}$ or $V_O < 0\text{ V}$	-	±50	mA
V_O	output voltage	note 1	-0.5	$V_{CC} + 0.5$	V
I_O	output source or sink current	$V_O = 0\text{ V to }V_{CC}$	-	±50	mA
I_{CC}, I_{GND}	V_{CC} or GND current		-	±100	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	power dissipation	$T_{amb} = -40\text{ °C to }+125\text{ °C}$; note 2	-	500	mW

Notes

- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- For SO14 packages: above 70 °C the value of P_{tot} derates linearly with 8 mW/K.
For (T)SSOP14 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.
For DHVQFN14 packages: above 60 °C the value of P_{tot} derates linearly with 4.5 mW/K.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. ⁽¹⁾	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = -40 °C to +85 °C							
V _{IH}	HIGH-level input voltage	V _{OL(max)} = 0.5 V; I _O = -100 μA	1.2	V _{CC}	-	-	V
			2.0	1.2	-	-	V
			2.7	1.8	-	-	V
			3.0	2.0	-	-	V
			3.6	2.4	-	-	V
V _{IL}	LOW-level input voltage	V _{OH(min)} = V _{CC} - 0.5 V; I _O = 100 μA	1.2	-	-	GND	V
			2.0	-	-	0.6	V
			2.7	-	-	0.6	V
			3.0	-	-	1.0	V
			3.6	-	-	1.2	V
V _{OH}	HIGH-level output voltage	V _{CC} or GND I _O = -12 mA I _O = -100 μA I _O = -12 mA I _O = -24 mA	2.7	V _{CC} - 0.5	-	-	V
			3.0	V _{CC} - 0.2	V _{CC}	-	V
			3.0	V _{CC} - 0.6	-	-	V
			3.0	V _{CC} - 1.0	-	-	V
V _{OL}	LOW-level output voltage	V _{CC} or GND I _O = 12 mA I _O = 100 μA I _O = 24 mA	2.7	-	-	0.40	V
			3.0	-	-	0.20	V
			3.0	-	-	0.55	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	3.6	-	±0.1	±5	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	3.6	-	0.1	10	μA

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP. ⁽¹⁾	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = -40 °C to +125 °C							
V _{IH}	HIGH-level input voltage	V _{OL(max)} = 0.5 V; I _O = -100 μA	1.2	V _{CC}	-	-	V
			2.0	1.6	-	-	V
			2.7	2.2	-	-	V
			3.0	2.4	-	-	V
			3.6	2.8	-	-	V
V _{IL}	LOW-level input voltage	V _{OH(min)} = V _{CC} - 0.5 V; I _O = 100 μA	1.2	-	-	GND	V
			2.0	-	-	0.4	V
			2.7	-	-	0.5	V
			3.0	-	-	0.6	V
			3.6	-	-	0.7	V
V _{OH}	HIGH-level output voltage	V _{CC} or GND I _O = -12 mA I _O = -100 μA I _O = -12 mA I _O = -24 mA	2.7	V _{CC} - 0.65	-	-	V
			3.0	V _{CC} - 0.3	V _{CC}	-	V
			3.0	V _{CC} - 0.75	-	-	V
			3.0	V _{CC} - 1.2	-	-	V
V _{OL}	LOW-level output voltage	V _{CC} or GND I _O = 12 mA I _O = 100 μA I _O = 24 mA	2.7	-	-	0.60	V
			3.0	-	-	0.30	V
			3.0	-	-	0.80	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	3.6	-	±0.1	±20	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A	3.6	-	0.1	40	μA

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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AC CHARACTERISTICS

GND = 0 V; $t_r = t_f \leq 2.5$ ns; $C_L = 50$ pF; $R_L = 500$ Ω .

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	V _{CC} (V)				
T_{amb} = -40 °C to +85 °C; note 1							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 6 and 9	1.2	–	6.0	–	ns
			2.7	0.5	2.4	4.5	ns
			3.0 to 3.6	0.5	2.1 ⁽²⁾	4.0	ns
t _{sk(0)}	skew	note 3		–	–	1.0	ns
T_{amb} = -40 °C to +125 °C							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 6 and 9	1.2	–	–	–	ns
			2.7	0.5	–	6.0	ns
			3.0 to 3.6	0.5	–	5.0	ns
t _{sk(0)}	skew	note 3	3.0 to 3.6	–	–	1.5	ns

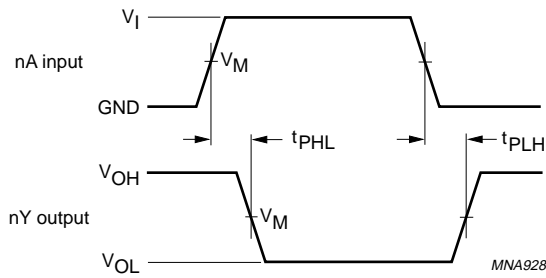
Notes

1. All typical values are measured at T_{amb} = 25 °C.
2. This typical value is measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.
3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

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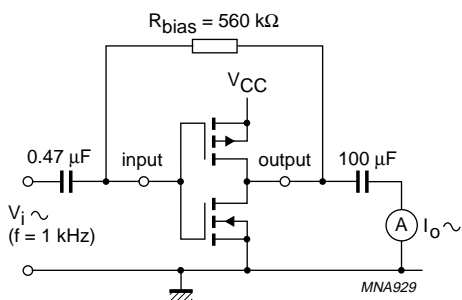
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AC WAVEFORMS



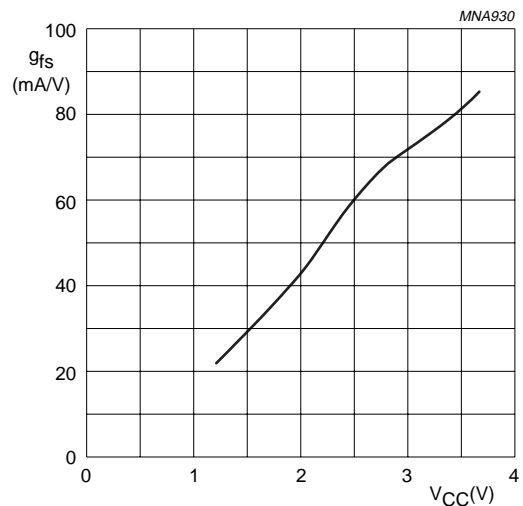
$V_M = 1.5 \text{ V}$ at $V_{CC} \geq 2.7 \text{ V}$.
 $V_M = 0.5 \times V_{CC}$ at $V_{CC} < 2.7 \text{ V}$.
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

Fig.6 Input (nA) to output (nY) propagation delays.



$$g_{fs} = \frac{dI_o}{dV_i}; \text{ at constant } V_o.$$

Fig.7 Test set-up for measuring forward transconductance.

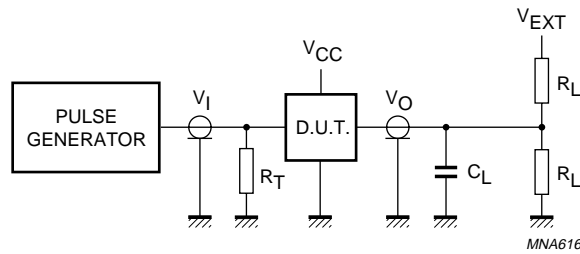


T_{amb} = 25 °C.

Fig.8 Typical forward transconductance as function of supply voltage.

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V _{CC}	V _I	C _L	R _L	V _{EXT}		
				t _{PLH} /t _{PHL}	t _{PZH} /t _{PHZ}	t _{PZL} /t _{PLZ}
1.2 V	V _{CC}	50 pF	500 Ω ⁽¹⁾	open	GND	2 × V _{CC}
2.7 V	2.7 V	50 pF	500 Ω	open	GND	2 × V _{CC}
3.0 V to 3.6 V	2.7 V	50 pF	500 Ω	open	GND	2 × V _{CC}

Note

1. The circuit performs better when R_L = 1 000 Ω.

Definitions for test circuit:

R_L = Load resistor.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig.9 Load circuitry for switching times.

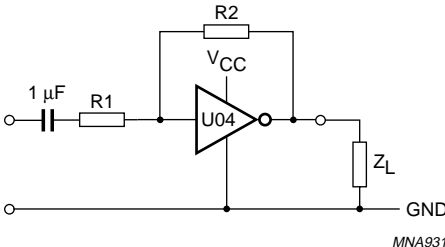
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APPLICATION DIAGRAM

Some applications for the 74LVCU04 are:

- Linear amplifier; see Fig.10
- Crystal oscillator designs; see Fig.11
- Astable multivibrator; see Fig.12.



MNA931

$Z_L > 10\text{ k}\Omega$.

$R_1 \geq 3\text{ k}\Omega, R_2 \leq 1\text{ M}\Omega$.

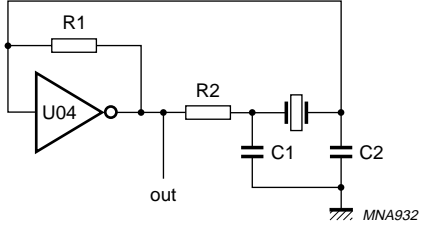
$V_{O(\text{max})(\text{p-p})} \approx V_{CC} - 1.5\text{ V}$ centred at $0.5 \times V_{CC}$.

Open loop amplification $A_{OL} = 20$ typical.

Voltage amplification $A_V = -\frac{A_{OL}}{1 + \frac{R_1}{R_2}(1 + A_{OL})}$

Typical unity gain bandwidth product is 5 MHz.

Fig.10 74LVCU04A used as linear amplifier.



MNA932

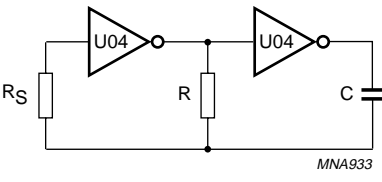
$C_1 = 47\text{ pF}$ (typical).

$C_2 = 22\text{ pF}$ (typical).

$R_1 = 1\text{ to }10\text{ M}\Omega$ (typical).

R_2 optimum value depends on the frequency and required stability against changes in V_{CC} or average minimum I_{CC} (I_{CC} is typically 2 mA at $V_{CC} = 3\text{ V}$ and $f = 1\text{ MHz}$).

Fig.11 74LVCU04A used as crystal oscillator.



MNA933

$f = \frac{1}{T} \approx \frac{1}{2.2RC}$

$R_S \approx 2R$.

The average I_{CC} is approximately $3.5 + 0.05f$ (MHz) \times C (pF) [mA] at $V_{CC} = 3.0\text{ V}$.

Fig.12 74LVCU04A used as astable multivibrator.

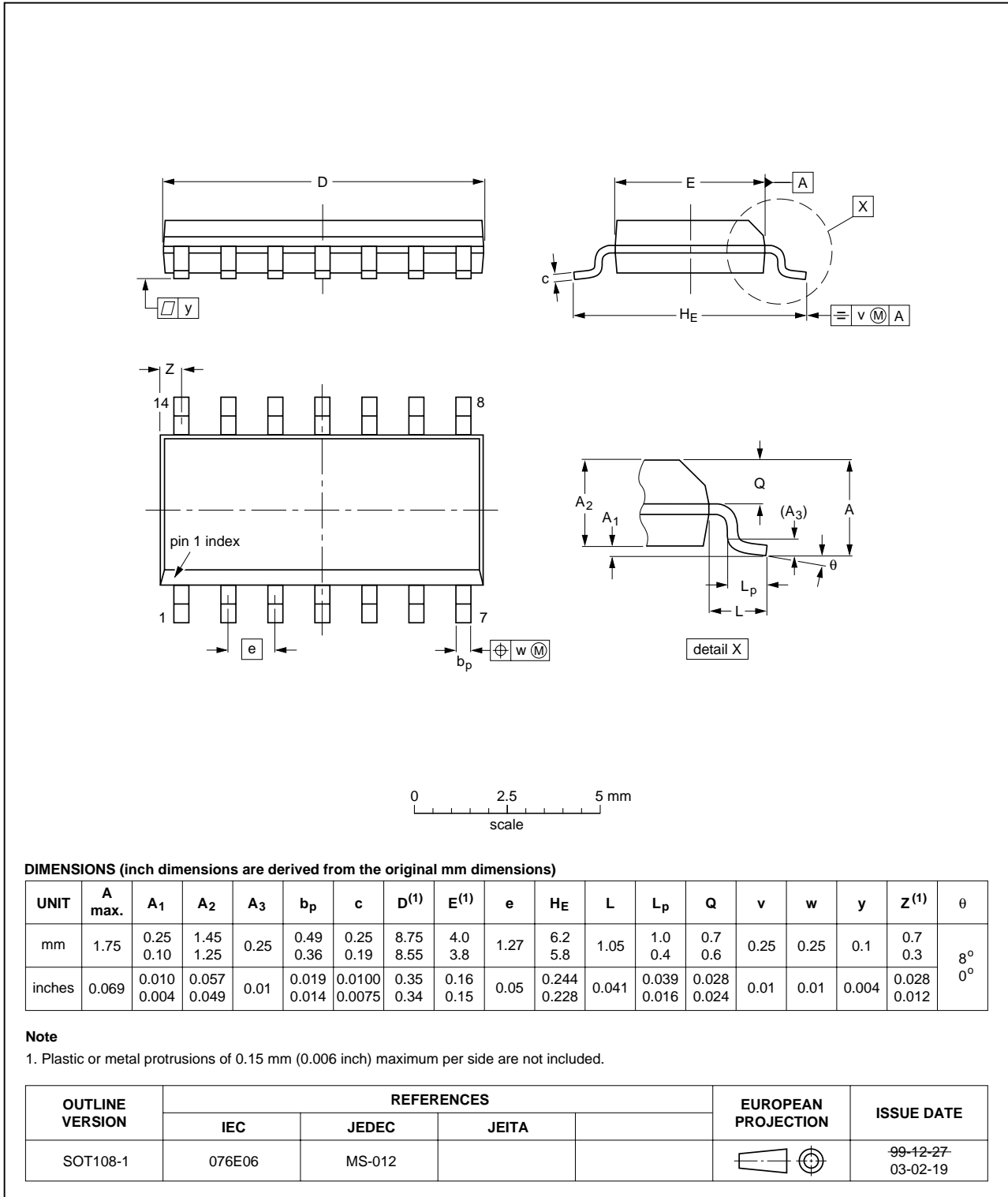
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PACKAGE OUTLINES

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

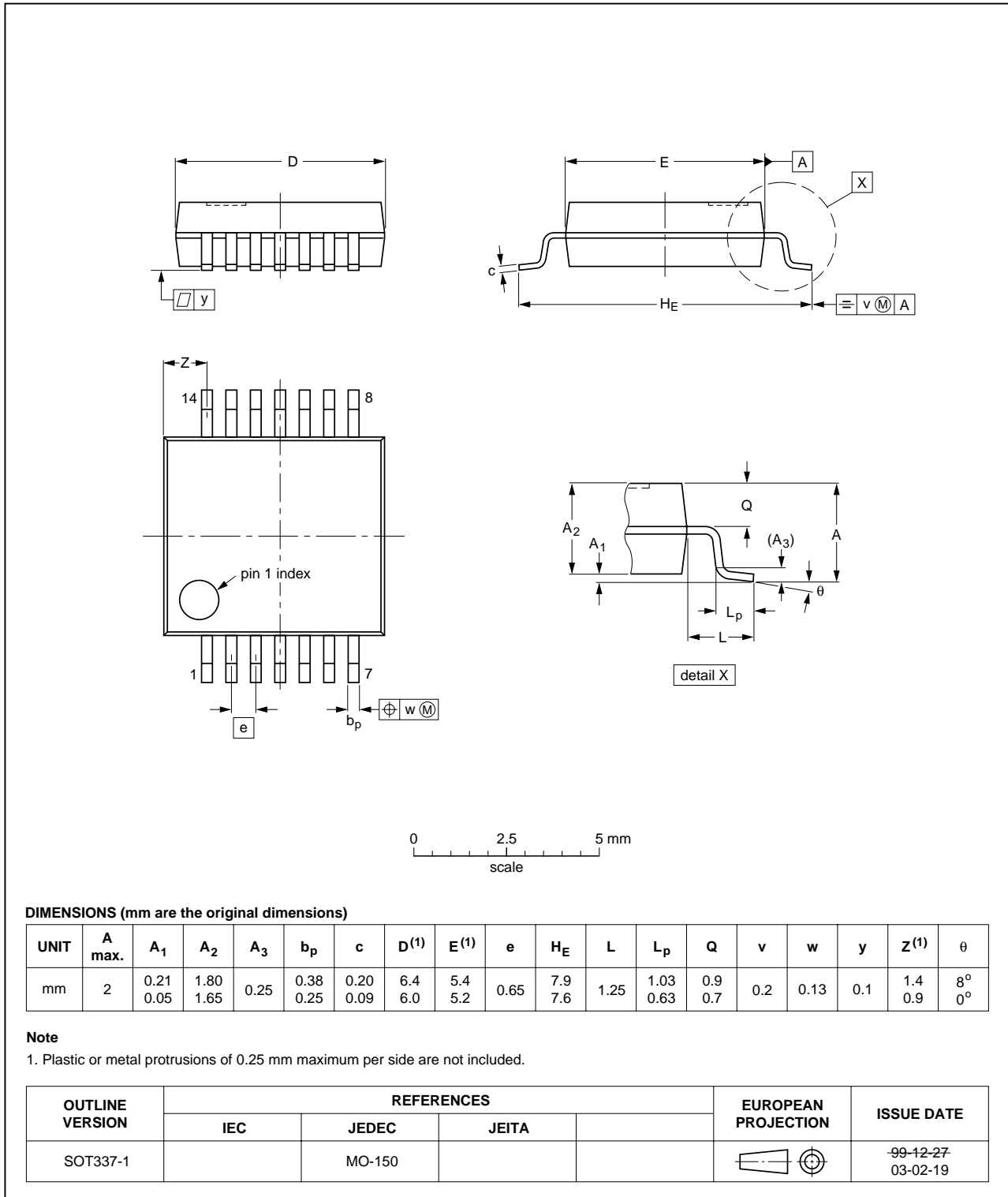


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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

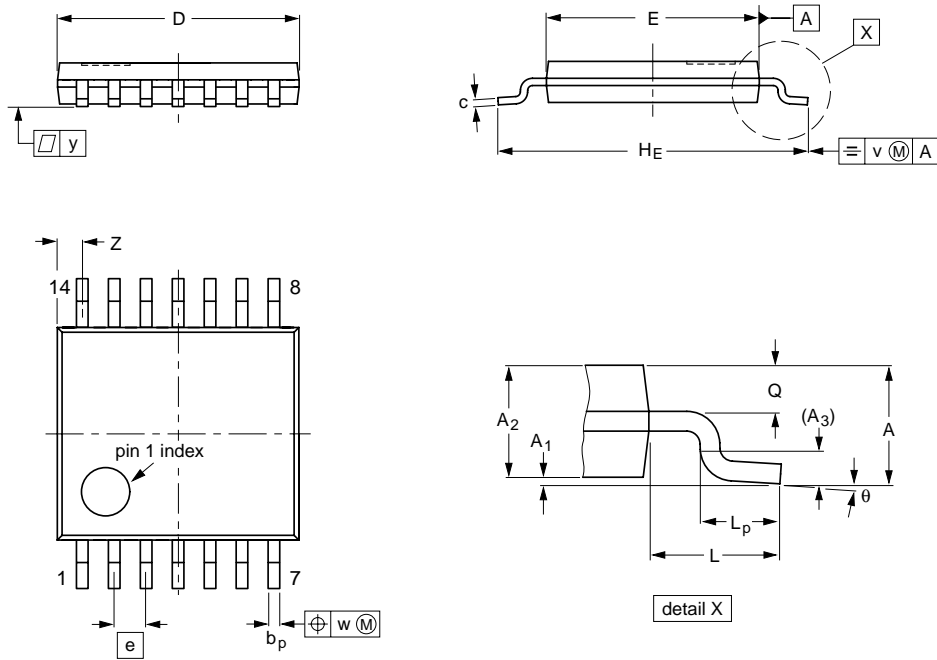


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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

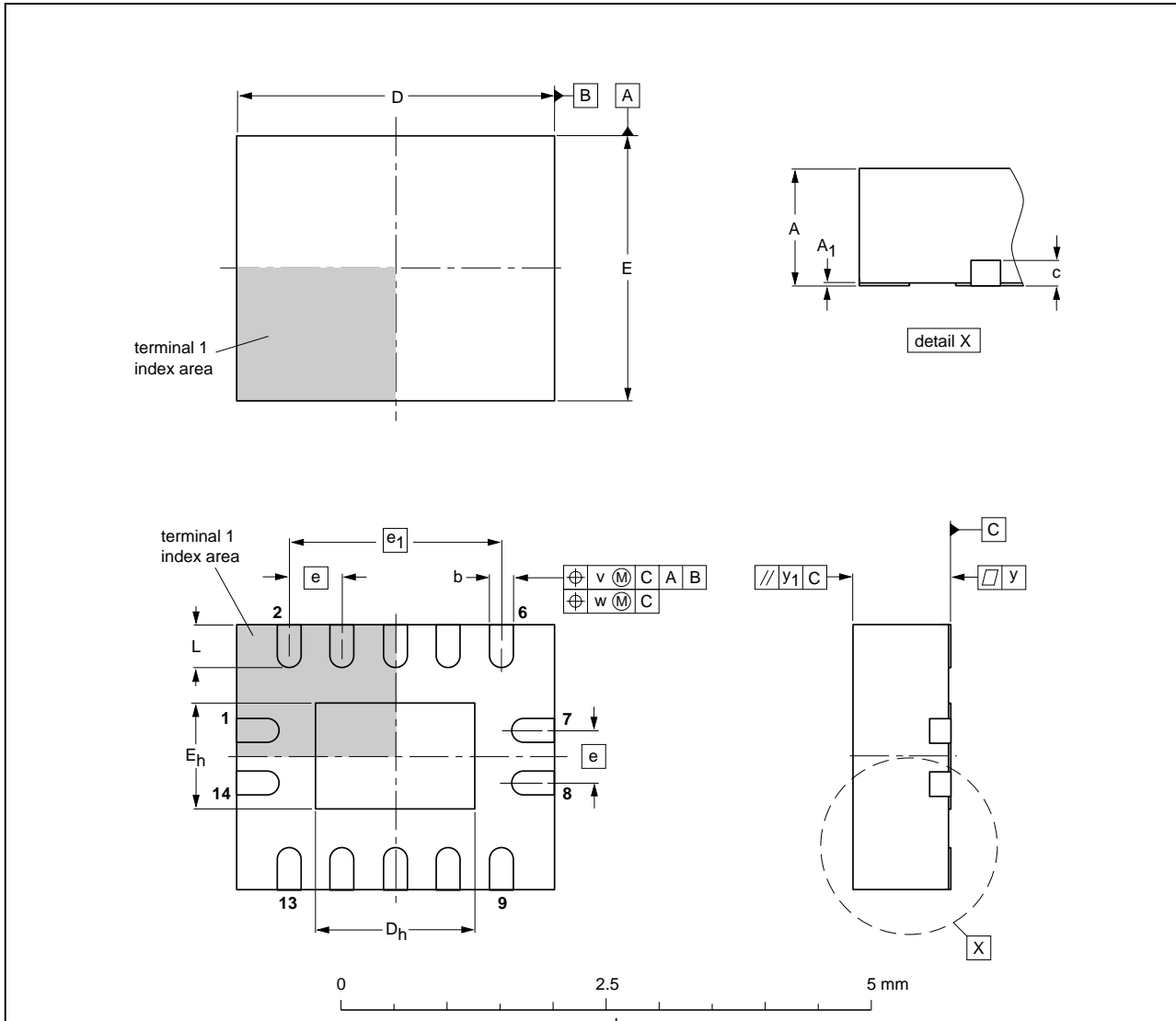
OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT402-1		MO-153			99-12-27 03-02-18

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm

SOT762-1



DIMENSIONS (mm are the original dimensions)

UNIT	A ⁽¹⁾ max.	A ₁	b	c	D ⁽¹⁾	D _h	E ⁽¹⁾	E _h	e	e ₁	L	v	w	y	y ₁
mm	1	0.05 0.00	0.30 0.18	0.2	3.1 2.9	1.65 1.35	2.6 2.4	1.15 0.85	0.5	2	0.5 0.3	0.1	0.05	0.05	0.1

Note

1. Plastic or metal protrusions of 0.075 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA		
SOT762-1	---	MO-241	---		02-10-17 03-01-27

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DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
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